



#### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	ID TA = +25°C
0.01/	1.5Ω @ V <sub>GS</sub> = 4.5V	0.5A
30V	2.0Ω @ V <sub>GS</sub> = 2.5V	0.43A

## **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Power-management functions
- Backlighting
- Load switches

#### DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

## **Features and Benefits**

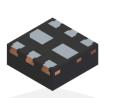
- Low On-Resistance
- Low Input/Output Leakage
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

## **Mechanical Data**

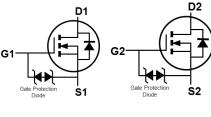
- Package: X2-DFN1010-6
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0015 grams (Approximate)



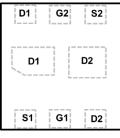


X2-DFN1010-6 (Type UXC)

**Bottom View** 



Equivalent Circuit



Pin-Out Top View

#### Ordering Information (Note 4)

Part Number	Pookago	Tape Width (mm)	Tape Pitch (mm)	Packing		
Fait Nulliber	Package	rape width (min)	Tape Filch (mm)	Qty.	Carrier	
DMN31D5UDR4-7	X2-DFN1010-6 (Type UXC)	8	4	5000	Tape & Reel	
DMN31D5UDR4-7R	X2-DFN1010-6 (Type UXC)	8	4	5000	Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

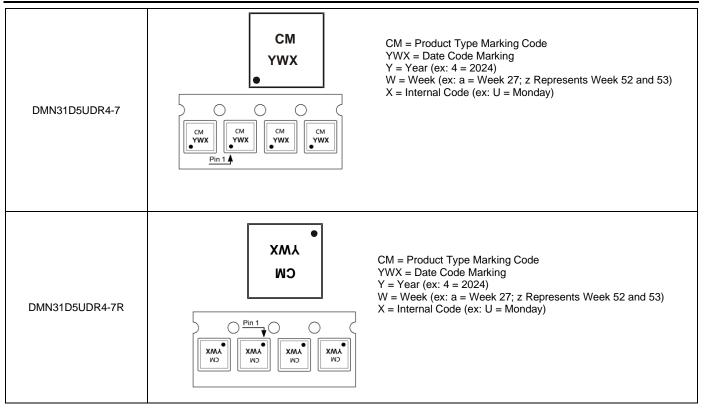
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**



Year	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034	2035
Code	4	5	6	7	8	9	0	1	2	3	4	5
· · · ·												
Week	1-26			27-52			53					
Code	A-Z			a-z			Z					
nternal Code	S	un	Mor	n	Tue	١	Ned	Thu	1	Fri		Sat
Code	-	Г	11		V		W	Х		V		7



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	30	V		
Gate-Source Voltage	Vgss	±12	V		
Continuous Drain Current (Note 5) V <sub>GS</sub> = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	ID	0.5 0.4	А
Maximum Continuous Body Diode Forward Current	ls	0.32	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	0.64	A		

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.37	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	335	°C/W
Total Power Dissipation (Note 6)		Po	0.66	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	188	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

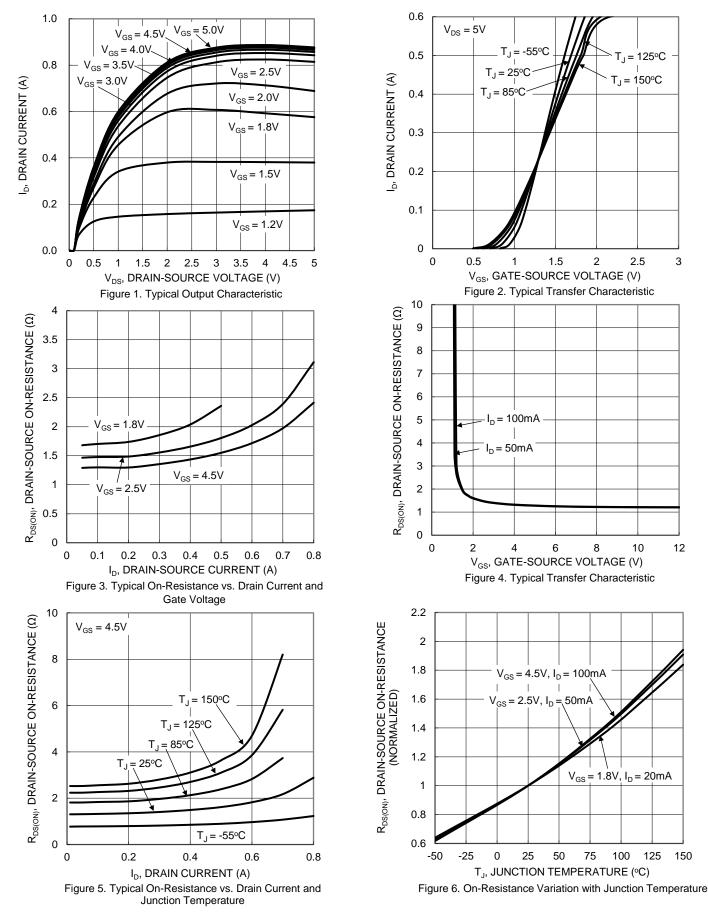
## Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	30	_		V	$V_{GS} = 0V, I_{D} = 10\mu A$
Zero Gate Voltage Drain Current	IDSS	_	—	100	nA	$V_{DS} = 24V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	—	±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)				•		
Gate Threshold Voltage	Vgs(th)	0.5	—	0.9	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
		_	1.3	1.5		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 100mA
Static Drain-Source On-Resistance	RDS(ON)	_	1.5	2.0	Ω	$V_{GS} = 2.5V, I_{D} = 50mA$
		_	1.7	3.0		$V_{GS} = 1.8V, I_D = 20mA$
Diode Forward Voltage	Vsd	_	0.8	1.0	V	Vgs = 0V, Is = 100mA
DYNAMIC CHARACTERISTICS (Note 8)			•	•		·
Input Capacitance	Ciss	_	22.2	—		
Output Capacitance	Coss	_	2.9	—	pF	$V_{DS} = 15V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	2.2	_		f = 1.0MHz
Total Gate Charge	Qg	_	0.05	—		
Gate-Source Charge	Q <sub>gs</sub>	_	0.02	—	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q <sub>gd</sub>	_	3.1	—		$I_D = 200 \text{mA}$
Turn-On Delay Time	t <sub>D(ON)</sub>	_	2.0	—		
Turn-On Rise Time	tR		20			V <sub>DD</sub> = 10V, V <sub>GS</sub> = 4.5V,
Turn-Off Delay Time	tD(OFF)	_	6.9	—	ns	$R_{G} = 6\Omega, I_{D} = 200 \text{mA}$
Turn-Off Fall Time	tF		22.2			

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing. Notes:

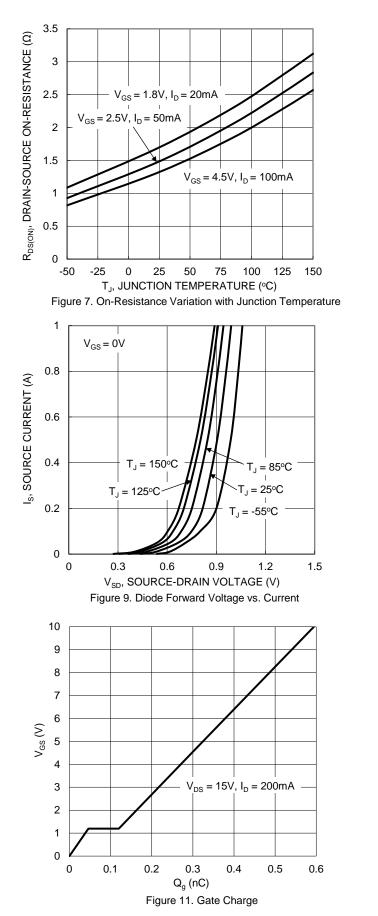


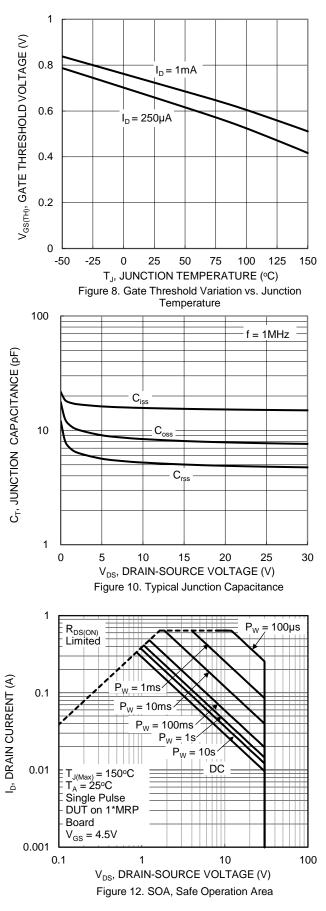
### DMN31D5UDR4





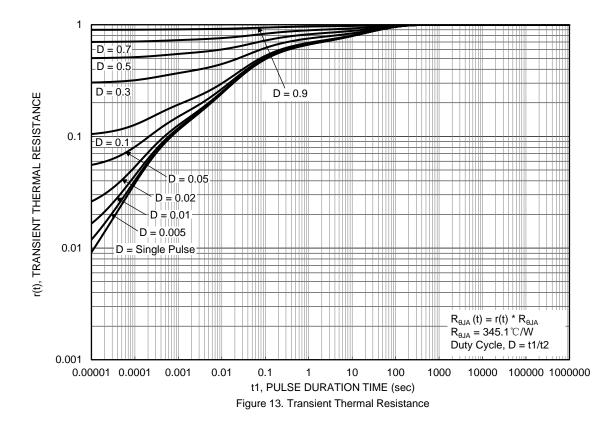
# DMN31D5UDR4





DMN31D5UDR4 Document number: DS46464 Rev. 2 - 2

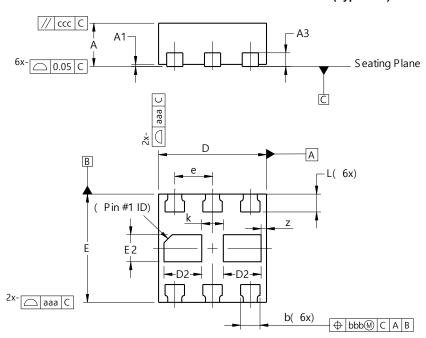






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

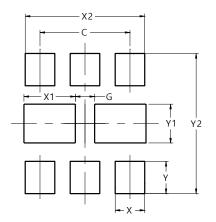


	X2-DFN1010-6 (Type UXC)							
Dim	Min	Max	Тур					
Α		0.40	0.39					
A1		0.05						
A3			0.127					
b	0.13	0.23	0.18					
D	0.95	1.05	1.00					
D2	0.30	0.40	0.35					
Е	0.95	1.05	1.00					
E2	0.20	0.30	0.25					
е	0.	350 BS	C					
L	0.115	0.215	0.165					
k			0.20					
z	0.02	0.08	0.05					
aaa	0.08							
bbb		0.07						
CCC		0.05						
All	Dimensi	ons in	mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X2-DFN1010-6 (Type UXC)



Dimensions	Value (in mm)
С	0.700
G	0.300
Х	0.230
X1	0.450
X2	0.930
Y	0.250
Y1	0.300
Y2	1.085



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